

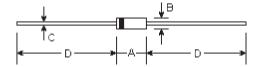
# **SB120 THRU SB1B0**

SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 20 to 100 Volts
Forward Current - 1.0 Ampere

### **Features**

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0 Flame retardant epoxy molding compound
- 1.0 ampere operation at T₁ =90°C with no thermal runaway
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications

DO-41



## **Mechanical Data**

• Case: Molded plastic, DO-41

• Terminals: Axial leads, solderable per

MIL-STD-202, method 208

• Polarity: Color band denotes cathode

Mounting Position: AnyWeight: 0.012 ounce, 0.33 gram

DIMENSIONS										
DIM	inc	hes	m	Note						
	Min.	Max.	Min.	Max.	Note					
Α	0.165	0.205	4.2	5.2						
В	0.079	0.106	2.0	2.7	ф					
С	0.028	0.034	0.71	0.86	ф					
D	1.000	-	25.40	-						

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

	Symbols	SB120	SB130	SB140	SB150	SB160	SB170	SB180	SB190	SB1B0	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	70	80	90	100	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	49	56	63	70	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	70	80	90	100	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at T_=90 $^{\circ}\mathrm{C}$	I <sub>(AV)</sub>	1.0								Amp	
Peak forward surge current, I <sub>M</sub> (surge): 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	k forward surge current, I <sub>M</sub> (surge): nS single half sine-wave superimposed ated load (MIL-STD-750D 4066 method)  I <sub>FSM</sub> 30.0						Amps				
Maximum forward voltage at 1.0A	V <sub>F</sub>	0.55 0.70 0.85						Volts			
Maximum full load reverse current, full cycle average at $\rm T_{\rm A} {=} 75  ^{\circ} \rm C$	I <sub>R(AV)</sub>	30.0								mA	
Maximum DC reverse current at rated DC blocking voltage $T_A^{=25}^{\circ}C$	I <sub>R</sub>	1.0 10.0								mA	
Typical junction capacitance (Note 1)	C <sub>J</sub>	110.0								ρF	
Typical thermal resistance (Note 2)	$R_{\scriptscriptstyle{\odotJA}}$	80.0								°C/W	
Operating and storage temperature range	$T_{J},T_{STG}$	-50 to +125								ပ္	

#### Notes:

- (1) Measured at 1.0MHz and applied reverse voltage of 4.0 VDC
- (2) Thermal resistance junction to ambient

## **RATINGS AND CHARACTERISTIC CURVES**

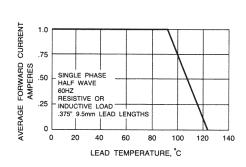


Fig. 1 - FORWARD CURRENT DERATING CURVE

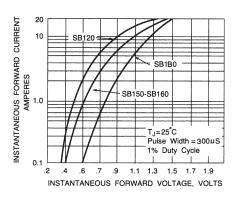


Fig. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

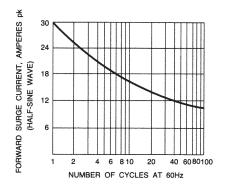


Fig. 3 - MAXIMUM NON-REPETITIVE SURGE CURRENT

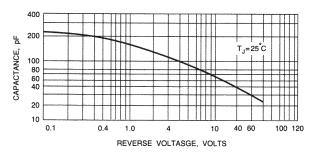


Fig. 4-TYPICAL JUNCTION CAPACITANCE